CERF	amate	TYPE	SMV0402EDDDDDDDDRR MODEL		PAGE	1
CITATION				DATE	Feb. 13, 2	200
SUBJECT			Structure	REV.	C01	
1.	STRUCT	URE				
NO.	ITE	EM	DESCRIPTION			ļ
1.1	Main N	laterial	Zinc Oxide			
1.2	End terr	mination	Ag/Ni/Sn			
1.3	Pack	aging	Reel			
1.4	-	es with idard	IEC61000-4-2 level 4			
1.5	Complies Stan	with Ro⊦ idard	S Yes			
1.6	Lead o	content	< 1000ppm			
1.7		lder prof erature nmend)	e 250 ℃			
			L	1.00	± 0.10	
			a W	0.50	± 0.10	
			T(max.)	(0.60	
1.8	Dimo	nsions	a	0.2	5 ± 0.1	
1.0	Dime	1310113	$\frac{1}{T_{c}}$ $\frac{1}{W_{c}}$ $(Unit : mm)$			

CCERAMATE	TYPE SMV0402E		PAGE	2/9
CITATION		DATE	Feb. 13, 2	2009
SUBJECT	Electrical Characteristics	REV.	C01	

2. ELECTRICAL CHARACTERISTICS

N0.	ITEM	PERFORMANCE	TEST METHODS
2.0	Standard Conditions		Unless otherwise specified, all tests are made under environmental conditions as given below: Temperature: 5~35°C Relative humidity: 45~85 % RH
2.1	Maximum Allowable Voltage	AC : *(1) V _{rms} DC : *(1) V	Maximum continuous sine wave(RMS) or DC voltage which may be applied.
2.2	Varistor Voltage	V _{0.1mA} : *(1) V	Voltage across the varistor measured at C_{mA} DC.
2.3	Varistor Voltage Temperature Coefficient	0 ~ –0.05 %/°C	<u>VemAæsse — VemAæzse</u> x <u>1</u> VemAæzse X <u>60</u> x 100
2.4	Max. Clamping Voltage	* (1) Vat 1 A	Peak voltage across the varistor with a specified peak impulse current of 8x20µs waveform.
2.5	ESD Trigger Voltage (V⊤)	<* (1) V	
2.6	Response time	T _{rise} < 1 nS	
2.7	Leakage current	I _{LDC} <*(1)μA I _{LDCA} <*(1)μA	at V1mA×80% at V1mA×80% (After ESD Test)
2.8	Capacitance	* (1) pF.	Capacitance shall be measured at 1 MHz,1 Vrms max. 0V bias and 20±2 $^\circ\!\mathrm{C}$

*(1) See table 2.1 Electrical Characteristics

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Table 2.1 Electrical Characteristics

Part Number		mum vable age	Varistor Voltage	Max. Clamping Voltage	ESD Trigger Voltage (V⊤)	Cur	kage rent A)	Typical	Capacitance
Symbol	AC	DC	V(1mA)	V	V	I_{LDC}	I _{LDCA}	PF(MHz)	Tolerance (%)
0402E0503R0PRR		5	48~73	<135		0.1	2	2.5	+80/-20
0402E050050PRR	3.3	5	28~38	<72		0.1	2	4~9	+80/-20
0402E050100NRR	3.3	5	28~38	<72		0.1	2	7~13	+30/-30
0402E050200NRR	3.3	5	18~28	<52		0.1	2	14~26	+30/-30
0402E050220NRR	3.3	5	18~28	<52		0.1	2	15.4~28.6	+30/-30
0402E050330NRR	3.3	5	18~28	<52		0.1	2	23.1~42.9	+30/-30
0402E050470NRR	3.3	5	18~28	<52		0.1	2	32.9~61.1	+30/-30
0402E050560NRR	3.3	5	18~28	<52		0.1	2	39.2~72.8	+30/-30
0402E050820NRR	3.3	5	18~28	<52		0.1	2	57.4~106.6	+30/-30
0402E050101NRR	3.3	5	18~28	<52		0.1	2	70~130	+30/-30
0402E120050PRR	8	12	28~38	<72		0.1	2	4~9	+80/-20
0402E120100NRR	8	12	28~38	<72		0.1	2	10	+30/-30
0402E120220NRR	8	12	20~30	<55		0.1	2	22	+30/-30
0402E120330NRR	8	12	20~30	<55		0.1	2	33	+30/-30
0402E120560NRR	8	12	20~30	<55		0.1	2	56	+30/-30
0402E120820NRR	8	12	20~30	<55		1	2	82	+30/-30
0402E120101NRR	8	12	20~30	<55		0.1	2	100	+30/-30
0402E1400R2PRR		14		<35	250	0.05	10	0.25	+200/-50
0402E140101NRR	10	14	27~42	<68		0.1	2	100	+30/-30
0402E1802R05PR		18	48~72	<145		0.1	2	2	+50/-50
0402E1803R0PRR		18	48~72	<200		0.1	2	3	+80/-20
0402E180100NRR	12	18	27~42	<60		0.1	2	10	+30/-30
0402E180220NRR	12	18	21~27	<60		0.1	2	22	+30/-30
0402E180101NRR	12	18	21~28	<68		0.1	2	100	+30/-30
0402E2400R8PRR		24	100~150	<200		0.1	2	0.8~1.5	+80/-20
0402E2402R5PRR	18	24	100~150	<200		0.1	2	2~4.5	+80/-20
0402E2403R0NRR		24	48~72	<200		0.1	2	3	+80/-20

* 0603E2400R2PRR : Minimum ESD pulse withstand 2000 times

${\cal C}$ ceramate	TYPE	SMV0402E	MODEL		PAGE	4/9
CITATION				DATE	Feb. 13, 2	2009
SUBJECT		Reliability		REV.	C01	

3. ENVIRONMENTAL CHARACTERISTICS

No.	Characteristic		Test m	ethod and description	1				
3.1	High Temperature Storage	The specimen shall be subjected to $150 \pm 2^{\circ}$ C for 1000 ± 12 hours in a thermostatic bath without load and then stored at room temperature and humidity for 1 to 2 hours. The change of varistor voltage shall be within 10%.							
		The temperature cycle of specified temperature shall be repeated five times	Step	Temperature -40±3℃	Period 30Min±3				
3.2	3.2 Temperature Cycle	and then stored at room temperature and humidity for one or two hours. The	2	Room Temperature	1~2 hours				
		change of varistor voltage shall be within	3	125±2 ℃	30Min±3				
		10% and mechanical damage shall be	4	Room Temperature	1~2 hours				
3.3	High Temperature Load	After being continuously applied the maxin hours, the specimen shall be stored at roo hours, the change of varistor voltage shall	m temp	erature and humidity fo					
3.4	Damp Heat Load/ Humidity Load	The specimen should be subjected to 40 ± maximum allowable voltage applied for 10 and humidity for one or two hours. The cha	00 hour	s, then stored at room t	emperature				
3.5	Low Temperature Storage		nd humidity for one or two hours. The change of varistor voltage shall be within 10%. The specimen should be subjected to $-40 \pm 2^{\circ}$, without load for 500 hours and then tored at room temperature for one or two hours. The change of varistor voltage shall be within 10%						

4. TECHNICAL TERM

No.	Item	Specifications	Description
4.1	Operating Temperature Range	-40°C to +85°C	Operating temperature range without derating.
4.2	Storage Temperature Range	-40℃ to +125℃	Storage temperature range without voltage applied.
4.3 w DataS	Transient Response heet4U.com	< 50 ns	Time lag between application of surge and varistor's "turn-on" conduction action.

CERAMATE	TYF	E SMV	/0402E⊏			PAGE	5/9
CITATION					DATE	Feb. 13, 2	2009
SUBJECT			Sol	dering	REV.	C01	
5.1 Recommended s		d layout C 0.5~0.6	D 0.6~1.2			- c -	

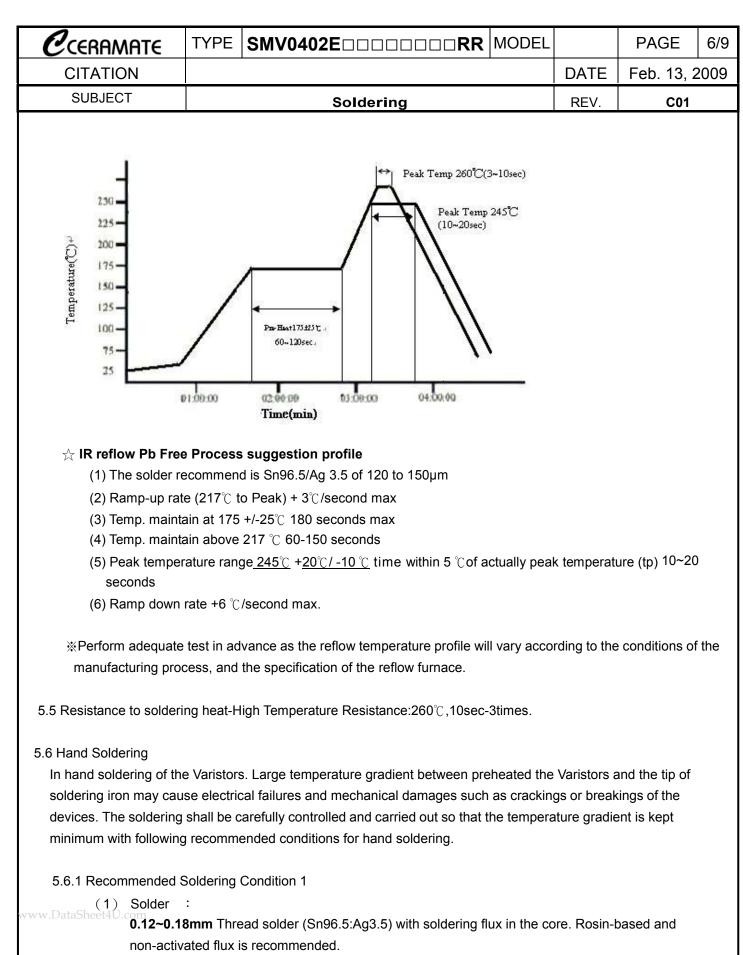
5.2 The SIR test of the solder paste shall be done (Based on JIS-Z-3284)

5.3 Steel plate and foot distance printing

Foot distance printing (mm)	Steel Plate thickness (mm)
> 0.65mm	0.18mm
0.65mm~0.5mm	0.15mm
0.50mm~0.40mm	0.12mm
<=0.40 mm	0.10mm

5.4 IR Soldering

Rapid heating, partial heating or rapid cooling will easily cause defect of the component. So preheating and gradual cooling process is suggested. IR soldering has the highest yields due to controlled heating rates and solder liquids times. Make sure that the element is not 2.4 The IR reflow and temperature of Soldering for Pb Free subjected to a thermal gradient steeper than 4 degrees per second. 2 degrees per second is the ideal gradient. During the soldering process, pre- heating to within 100 degrees of the solders peak temperature is essential to minimize thermal shock.



(2) Preheating

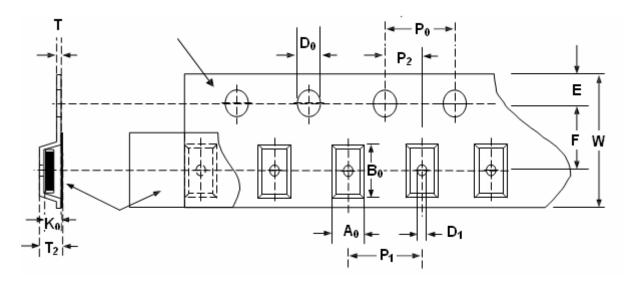
The Varistors shall be preheated so that Temperature Gradient between the devices and the tip of soldering iron is 150° C or below.

CERAMATE	TYPE	SMV0402E	IDDDDDD RR MODEL		PAGE	7/9		
CITATION				DATE	Feb. 13, 1	2009		
SUBJECT		Sold	ering	REV. C01				
Temperat in advance (4) Cooling After sold 5.6.2 Recommended a (1) Solder iron (2) Solder iron electrode 5.7 Post Soldering Clea 5.7.1 Residues of con electrical chara mounted on the affected by the 5.7.2. When an ultrase recommended	ower of 20v ature of sold ace on the s dering. The Soldering (on tip shall i on tip shall i e of Varisto aning prrosive sole acteristic ar e board. It sonic clean for preven ised by the ncy 29MHz ed Power 20	e Varistors shall be co Condition 2 (Without not directly touch to c be fully preheated bef rs. dering fluxes on the F nd the reliability (such shall be confirmed that eaning conditions. ing is applied to the ting failures or damag ultrasonic waves.	nax,3-5sec (The required amou oled gradually at room ambient	temperatur on tip to the atly have ir aristors wh ability of the ds. Followi	e. e external fluences on ich have bee e devices are	the n e not s are		

${\cal C}$ ceramate	TYPE	SMV0402E	MODEL		PAGE	8/9
CITATION				DATE	Feb. 13, 2	2009
SUBJECT		Packaging Specificatio	n	REV.	C01	

6. PACKAGING SPECIFICATION

- 6.1 Carrier tape and transparent cover tape should be heat-sealed to carry the products, and the reel should be used to reel the carrier tape.
- 6.2 The adhesion of the heat-sealed cover tape shall be 40 +20/ -15grams.
- 6.3 Both the head and the end portion of the taping shall be empty for reel package and SMT auto-pickup machine. And a normal paper tape shall be connected in the head of taping for the operator to handle



Symb	ol	A0 ±0.05	B0 ±0.05	K0 ±0.05	T ±0.05	T2 ±0.05	D0 +0.10 -0.05	D1 ±0.05	P1 ±0.10	P2 ±0.10	P0 ±0.10	W ±0.10	E ±0.10	F ±0.05
m	n	1.10	1.90	0.95	0.22	1.26	1.56	1.00	4.00	2.00	4.00	8.00	1.75	3.50

CCERAMAT	ε τγρ	ESMV	/0402E [NODEL		PAGE	9/9
CITATION							DATE	Feb. 13, 2	2009
SUBJECT			Reel D)imens	ion		REV.	C01	
			E	C D	В		W1		
Symbol	A	В	А С	D	E	w	W ₁		
Unit(mm)	178±1	60±0.5	13±0.2	21±0.2	2.0±0.5	9±0.5	1.5±0.15	5	
	backaging :	1000 pcs	/Reel.						
	backaging :	1000 pcs	/Reel.						